

Roberto Paiella

List of Publications by Year in descending order

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93
papers

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186265

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95
all docs

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docs citations

95
times ranked

2534
citing authors

#	ARTICLE	IF	CITATIONS
1	Graphene plasmonic terahertz lamps. , 2021, , .		0
2	Plasmonic Directional Photodetectors for Edge Enhancement. , 2021, , .		0
3	Strain-Induced Lateral Heterostructures in Patterned Semiconductor Nanomembranes for Micro- and Optoelectronics. ACS Applied Nano Materials, 2021, 4, 6160-6169.	5.0	2
4	Plasmonic Metasurfaces for Directional Light Emission and Photodetection. , 2021, , .		0
5	Tunable terahertz metasurface platform based on CVD graphene plasmonics. Optics Express, 2021, 29, 40594.	3.4	3
6	Terahertz radiation processes in critically coupled graphene plasmonic nanostructures. Journal of Applied Physics, 2020, 128, .	2.5	5
7	Geometrically Tunable Beamed Light Emission from a Quantumâ€• Ensemble Near a Gradient Metasurface. Advanced Optical Materials, 2020, 8, 1901951.	7.3	12
8	Plasmonic ommatidia for lensless compound-eye vision. Nature Communications, 2020, 11, 1637.	12.8	51
9	Graphene plasmonic devices for terahertz optoelectronics. Nanophotonics, 2020, 9, 1901-1920.	6.0	59
10	Plasmonic Computational Compound-Eye Camera. Optics and Photonics News, 2020, 31, 41.	0.5	0
11	Plasmonic Metasurfaces for the Near-Field Directional Control of Spontaneous Light Emission. , 2020, , .		0
12	Tunable Terahertz Light Emission from Current-Driven Graphene Plasmonic Oscillators. , 2020, , .		0
13	Current-Driven Terahertz Light Emission from Graphene Plasmonic Oscillations. ACS Photonics, 2019, 6, 2562-2569.	6.6	32
14	A Polarization Insensitive Wideâ€•Band Perfect Absorber. Advanced Engineering Materials, 2019, 21, 1900188.	3.5	11
15	Correction to â€œInterminiband Optical Transitions in Graphene Lateral Superlatticesâ€•. ACS Photonics, 2019, 6, 238-239.	6.6	0
16	Giant distributed optical-field enhancements from Mie-resonant lattice surface modes in dielectric metasurfaces. OSA Continuum, 2019, 2, 32.	1.8	18
17	Ultrawide Strain Tuning of Luminescence from Mechanically Stressed InGaAs Nanomembranes. , 2019, , .		0
18	Ultrawide strain-tuning of light emission from InGaAs nanomembranes. Applied Physics Letters, 2018, 113, 201105.	3.3	11

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19	Optical Properties of Tensilely Strained Ge Nanomembranes. <i>Nanomaterials</i> , 2018, 8, 407.	4.1	2
20	Interminiband Optical Transitions in Graphene Lateral Superlattices. <i>ACS Photonics</i> , 2018, 5, 3331-3337.	6.6	2
21	Directional Plasmonic Image Sensors for Lens-Free Compound-Eye Vision. , 2018, , .		1
22	Beamed Light Emission near a Gradient Metasurfaces. , 2018, , .		0
23	Deep-Ultraviolet Emitting AlGaIn Multiple Quantum Well Graded-Index Separate-Confinement Heterostructures Grown by MBE on SiC Substrates. <i>IEEE Photonics Journal</i> , 2017, 9, 1-9.	2.0	27
24	Graphene Terahertz Plasmons: A Combined Transmission Spectroscopy and Raman Microscopy Study. <i>ACS Photonics</i> , 2017, 4, 2011-2017.	6.6	15
25	Optoelectronic device physics and technology of nitride semiconductors from the UV to the terahertz. <i>Reports on Progress in Physics</i> , 2017, 80, 106501.	20.1	165
26	GaN Terahertz Photodetectors for the Reststrahlen Gap of Intersubband Optoelectronics. , 2017, , .		0
27	III-nitride terahertz photodetectors for the Reststrahlen gap of intersubband optoelectronics. , 2017, , .		0
28	Quantification of Multiple Molecular Fingerprints by Dual-Resonant Perfect Absorber. <i>Advanced Optical Materials</i> , 2016, 4, 1274-1280.	7.3	56
29	Terahertz intersubband photodetectors based on semi-polar GaN/AlGaIn heterostructures. <i>Applied Physics Letters</i> , 2016, 108, .	3.3	42
30	Flexible nanomembrane photonic-crystal cavities for tensilely strained-germanium light emission. <i>Applied Physics Letters</i> , 2016, 108, 241107.	3.3	10
31	SiGe Nanomembrane Quantum-Well Infrared Photodetectors. <i>ACS Photonics</i> , 2016, 3, 1978-1985.	6.6	22
32	One-dimensional carbon nanostructures for terahertz electron-beam radiation. <i>Physical Review B</i> , 2016, 93, .	3.2	2
33	Light Emission near a Gradient Metasurface. <i>ACS Photonics</i> , 2016, 3, 243-248.	6.6	8
34	Mechanically Flexible Photonic-Crystal Cavities on Strained Germanium Fabricated by Nanomembrane Assembly. , 2016, , .		0
35	Uniaxial Strain Redistribution in Corrugated Graphene: Clamping, Sliding, Friction, and 2D Band Splitting. <i>Nano Letters</i> , 2015, 15, 5969-5975.	9.1	31
36	Graphene on nanoscale gratings: a novel materials platform for THz electron-beam radiation. , 2015, , .		1

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37	Graphene on nanoscale gratings for terahertz Smith-Purcell radiation. , 2015, , .		0
38	Graphene on nanoscale gratings for the generation of terahertz Smith-Purcell radiation. Applied Physics Letters, 2014, 105, .	3.3	24
39	Tensilely strained germanium nanomembranes for direct-bandgap infrared light emission. Proceedings of SPIE, 2014, , .	0.8	1
40	Mechanically Flexible Photonic-Crystal Cavities on Strained-Germanium Nanomembranes. , 2014, , .		0
41	Numerical simulation of III-nitride lattice-matched structures for quantum cascade lasers. , 2014, , .		3
42	Strained-Germanium Nanostructures for Infrared Photonics. ACS Nano, 2014, 8, 3136-3151.	14.6	80
43	Graphene electronics for terahertz electron-beam radiation. Nanotechnology, 2013, 24, 375205.	2.6	22
44	Strain Engineered SiGe Multiple-Quantum-Well Nanomembranes for Far-Infrared Intersubband Device Applications. ACS Nano, 2013, 7, 2326-2334.	14.6	22
45	Tensilely Strained Germanium Nanomembranes as Infrared Optical Gain Media. Small, 2013, 9, 622-630.	10.0	52
46	Development of AlGaN-based graded-index-separate-confinement-heterostructure deep UV emitters by molecular beam epitaxy. Journal of Vacuum Science and Technology B:Nanotechnology and Microelectronics, 2013, 31, .	1.2	33
47	Sub-250nm light emission and optical gain in AlGaN materials. Journal of Applied Physics, 2013, 113, .	2.5	24
48	Plasmonic off-axis unidirectional beaming of quantum-well luminescence. Applied Physics Letters, 2013, 103, .	3.3	18
49	Grating-coupled mid-infrared light emission from tensilely strained germanium nanomembranes. Applied Physics Letters, 2013, 103, 201114.	3.3	18
50	Plasmon-enhanced light emission based on lattice resonances of silver nanocylinder arrays. Optics Letters, 2012, 37, 79.	3.3	42
51	Sub-250 nm room-temperature optical gain from AlGaN/AlN multiple quantum wells with strong band-structure potential fluctuations. Applied Physics Letters, 2012, 100, 061111.	3.3	52
52	Polarization Properties of Deep-Ultraviolet Optical Gain in Al-Rich AlGaN Structures. Applied Physics Express, 2012, 5, 032103.	2.4	13
53	Far-infrared intersubband photodetectors based on double-step III-nitride quantum wells. Applied Physics Letters, 2012, 100, 241113.	3.3	60
54	Plasmonic dispersion engineering of coupled metal nanoparticle-film systems. Journal of Applied Physics, 2012, 111, 103102.	2.5	11

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55	Sequential tunneling transport in GaN/AlGaIn quantum cascade structures. <i>Physica Status Solidi C: Current Topics in Solid State Physics</i> , 2012, 9, 588-591.	0.8	3
56	Going ultrafast. <i>Nature Photonics</i> , 2011, 5, 253-255.	31.4	3
57	Electroabsorption modulators based on bulk GaN films and GaN/AlGaIn multiple quantum wells. <i>Journal of Applied Physics</i> , 2011, 109, 083102.	2.5	11
58	Direct-bandgap light-emitting germanium in tensilely strained nanomembranes. <i>Proceedings of the National Academy of Sciences of the United States of America</i> , 2011, 108, 18893-18898.	7.1	219
59	Direct-Bandgap Germanium Active Layers Pumped Above Transparency Based on Tensilely Strained Nanomembranes. , 2011, , .		1
60	Plasmon-Enhanced Near-Green Light Emission from InGaIn/GaN Quantum Wells. <i>ECS Meeting Abstracts</i> , 2011, , .	0.0	0
61	Intersubband device applications of nitride quantum structures. , 2010, , .		1
62	Intersubband transitions in GaN-based quantum wells: a new materials platform for infrared device applications. <i>Proceedings of SPIE</i> , 2010, , .	0.8	0
63	Numerical Simulation of ZnO-Based Terahertz Quantum Cascade Lasers. <i>Journal of Electronic Materials</i> , 2010, 39, 1097-1103.	2.2	8
64	Optical and structural characterization of GaN/AlGaIn quantum wells for intersubband device applications. <i>Physica Status Solidi C: Current Topics in Solid State Physics</i> , 2010, 7, 2394-2397.	0.8	3
65	Enhanced near-green light emission from InGaIn quantum wells by use of tunable plasmonic resonances in silver nanoparticle arrays. <i>Optics Express</i> , 2010, 18, 21322.	3.4	69
66	Multiple-junction quantum cascade photodetectors for thermophotovoltaic energy conversion. <i>Optics Express</i> , 2010, 18, 1618.	3.4	27
67	Sequential tunneling transport characteristics of GaN/AlGaIn coupled-quantum-well structures. <i>Journal of Applied Physics</i> , 2010, 108, 103704.	2.5	22
68	Plasmon enhanced light emission from InGaIn quantum wells via coupling to chemically synthesized silver nanoparticles. <i>Applied Physics Letters</i> , 2009, 95, 151109.	3.3	30
69	Optically pumped intersubband emission of short-wave infrared radiation with GaN/AlN quantum wells. <i>Applied Physics Letters</i> , 2009, 94, 081120.	3.3	34
70	Experimental Observation of Sequential Tunneling Transport in GaN/AlGaIn Coupled Quantum Wells Grown on a Free-Standing GaN Substrate. <i>Materials Research Society Symposia Proceedings</i> , 2009, 1202, 232.	0.1	0
71	Monte Carlo simulation of terahertz quantum cascade laser structures based on wide-bandgap semiconductors. <i>Journal of Applied Physics</i> , 2009, 105, .	2.5	98
72	Short-Wavelength Intersubband Light Emission from Optically Pumped GaN/AlN Quantum Wells. <i>Materials Research Society Symposia Proceedings</i> , 2009, 1202, 257.	0.1	0

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73	Refractive-index nonlinearities of intersubband transitions in GaN/AlN quantum-well waveguides. Journal of Applied Physics, 2008, 104, 083101.	2.5	15
74	Monte Carlo study of GaN versus GaAs terahertz quantum cascade structures. Applied Physics Letters, 2008, 92, .	3.3	98
75	Monte Carlo study of the temperature dependent performance of GaN versus GaAs terahertz quantum cascade structures. , 2008, , .		0
76	Intersubband nonlinear optical processes in GaN/AlN quantum-well waveguides. , 2008, , .		0
77	GaN/AlN Nonlinear Optical Waveguides for Ultrafast Intersubband All-Optical Switching. Conference Proceedings - Lasers and Electro-Optics Society Annual Meeting-LEOS, 2007, , .	0.0	1
78	Intersubband absorption in AlN/GaN/AlGaIn coupled quantum wells. Applied Physics Letters, 2007, 91, 141104.	3.3	37
79	AlN/GaN/AlGaIn Coupled Quantum Wells for Short-Wavelength Intersubband Devices. Conference Proceedings - Lasers and Electro-Optics Society Annual Meeting-LEOS, 2007, , .	0.0	0
80	Nonlinear optical waveguides based on near-infrared intersubband transitions in GaN/AlN quantum wells. Optics Express, 2007, 15, 5860.	3.4	40
81	Ultrafast all-optical switching with low saturation energy via intersubband transitions in GaN/AlN quantum-well waveguides. Optics Express, 2007, 15, 17922.	3.4	67
82	Intersubband all-optical switching based on Coulomb-induced optical nonlinearities in GaN/AlGaIn coupled quantum wells. Semiconductor Science and Technology, 2006, 21, 1105-1110.	2.0	15
83	Silicon-based injection lasers using electronic intersubband transitions in the L valleys. Applied Physics Letters, 2006, 89, 191110.	3.3	45
84	Silicon-Based Quantum Cascade Lasers using Electronic Intersubband Transitions in the L Valleys. , 2006, , .		0
85	Investigation of the design parameters of AlN/GaN multiple quantum wells grown by molecular beam epitaxy for intersubband absorption. Journal of Crystal Growth, 2005, 278, 387-392.	1.5	34
86	Tunable surface plasmons in coupled metallo-dielectric multiple layers for light-emission efficiency enhancement. Applied Physics Letters, 2005, 87, 111104.	3.3	63
87	High-frequency modulation without the relaxation oscillation resonance in quantum cascade lasers. Applied Physics Letters, 2001, 79, 2526-2528.	3.3	131
88	Monolithic active mode locking of quantum cascade lasers. Applied Physics Letters, 2000, 77, 169-171.	3.3	53
89	High-speed operation of gain-switched midinfrared quantum cascade lasers. Applied Physics Letters, 1999, 75, 2536-2538.	3.3	32
90	Four-wave mixing mediated by the capture of electrons and holes in semiconductor quantum-well laser amplifiers. Applied Physics Letters, 1997, 71, 3601-3603.	3.3	1

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91	Measurement of the interwell carrier transport lifetime in multi-quantum-well optical amplifiers by polarization-resolved four-wave mixing. Applied Physics Letters, 1996, 69, 4142-4144.	3.3	13
92	Highly nondegenerate four-wave mixing efficiency of an asymmetric coupled quantum well structure. Applied Physics Letters, 1995, 66, 2619-2621.	3.3	8
93	Intersubband Absorption in AlGaIn/GaN Quantum Wells. , 0, , 117-143.		6